

SILICON POWER TRANSISTOR

2SC2334

PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SC2334 is a mold power transistor developed for high-speed switching, and is ideal for use as a driver in devices such as switching regulators, DC/DC converters, and high-frequency power amplifiers.

FEATURES

- Low collector saturation voltage
- Fast switching speed
- Complementary transistor: 2SA1010

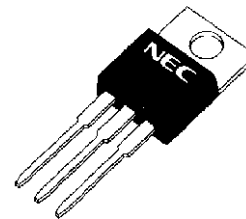
ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to base voltage	V_{CBO}		150	V
Collector to emitter voltage	V_{CEO}		100	V
Emitter to base voltage	V_{EBO}		7.0	V
Collector current (DC)	$I_{C(DC)}$		7.0	A
Collector current (pulse)	$I_{C(pulse)}$	$PW \leq 300 \mu s$, duty cycle $\leq 10\%$	15	A
Base current (DC)	$I_{B(DC)}$		3.5	A
Total power dissipation	P_T	$T_C = 25^\circ\text{C}$	40	W
		$T_A = 25^\circ\text{C}$	1.5	W
Junction temperature	T_j		150	$^\circ\text{C}$
Storage temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

ORDERING INFORMATION

Part No.	Package
2SC2334	TO-220AB

(TO-220AB)



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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

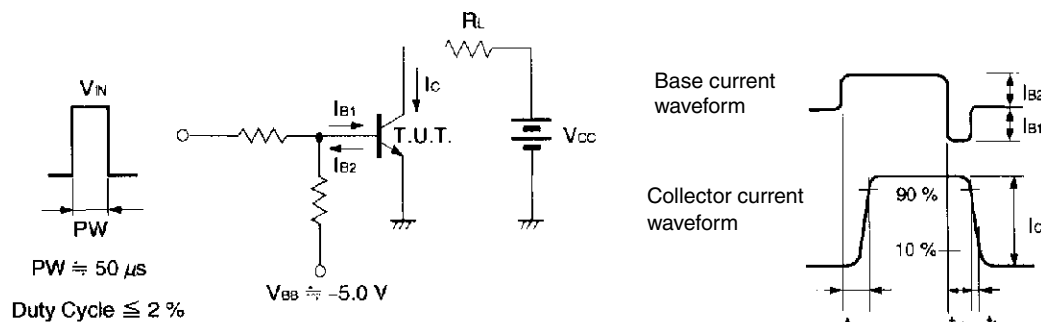
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	V _{CE0(SUS)}	I _C = 5.0 A, I _{B1} = 0.5 A, L = 1 mH	100			V
	V _{CEX(SUS)1}	I _C = 5.0 A, I _{B1} = -I _{B2} = 0.5 A, V _{BE(OFF)} = -5.0 V, L = 180 μH, clamped	100			V
	V _{CEX(SUS)2}	I _C = 10 A, I _{B1} = 1.0 A, I _{B2} = -0.5 A, V _{BE(OFF)} = -5.0 V, L = 180 μH, clamped	100			V
Collector cutoff current	I _{CBO}	V _{CB} = 100 V, I _E = 0 A			10	μA
	I _{CER}	V _{CE} = 100 V, R _{BE} = 51 Ω, T _A = 125°C			1.0	mA
	I _{CEX1}	V _{CE} = 100 V, V _{BE(OFF)} = -1.5 V			10	μA
	I _{CEX2}	V _{CE} = 100 V, V _{BE(OFF)} = -1.5 V, T _A = 125°C			1.0	mA
Emitter cutoff current	I _{EBO}	V _{EB} = 5.0 V, I _C = 0 A			10	μA
DC current gain	h _{FE1}	V _{CE} = 5.0 V, I _C = 0.5 A ^{Note}	40			
	h _{FE2}	V _{CE} = 5.0 V, I _C = 3.0 A ^{Note}	40		200	
	h _{FE3}	V _{CE} = 5.0 V, I _C = 5.0 A ^{Note}	20			
Collector saturation voltage	V _{CE(sat)}	I _C = 5.0 A, I _B = 0.5 A ^{Note}			0.6	V
Base saturation voltage	V _{BE(sat)}	I _C = 5.0 A, I _B = 0.5 A ^{Note}			1.5	V
Turn-on time	t _{on}	I _C = 5.0 A, R _L = 10 Ω, I _{B1} = -I _{B2} = -0.5 A, V _{CC} ≅ 50 V Refer to the test circuit.			0.5	μs
Storage time	t _{stg}				1.5	μs
Fall time	t _f				0.5	μs

Note Pulse test PW ≤ 350 μs, duty cycle ≤ 2%

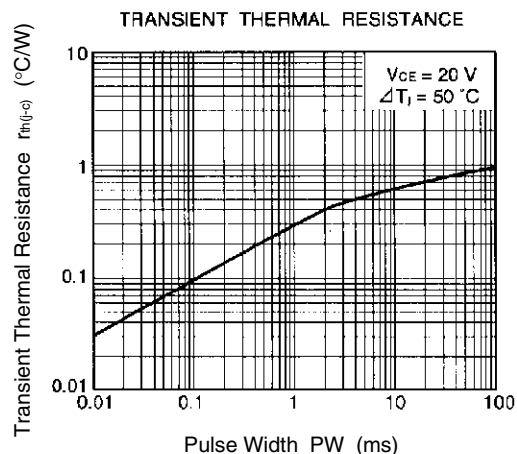
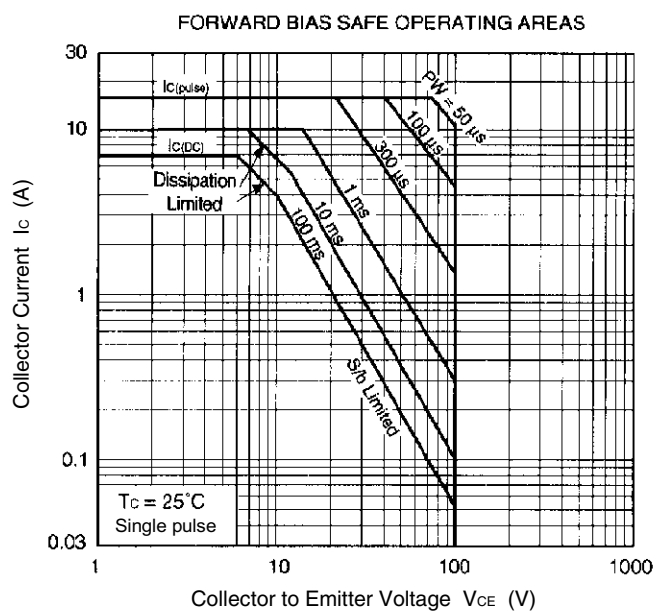
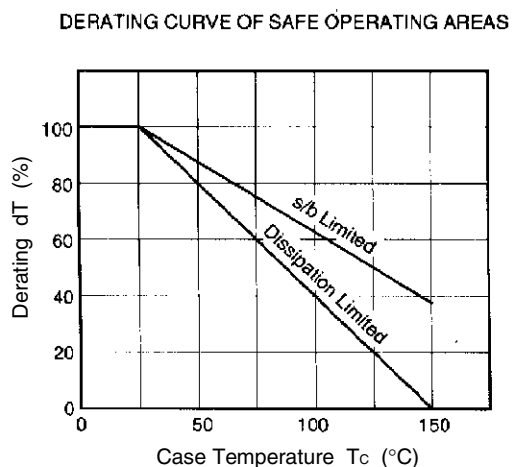
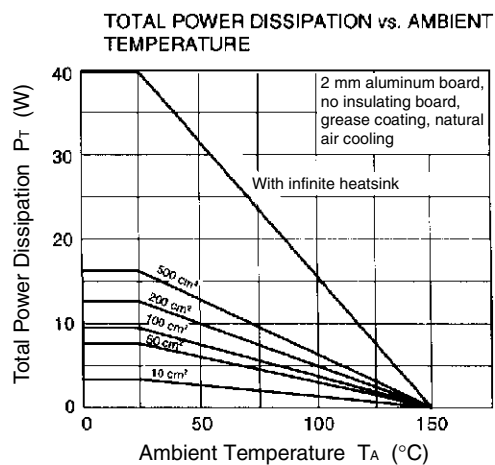
h_{FE} CLASSIFICATION

Marking	M	L	K
h _{FE2}	40 to 80	60 to 120	100 to 200

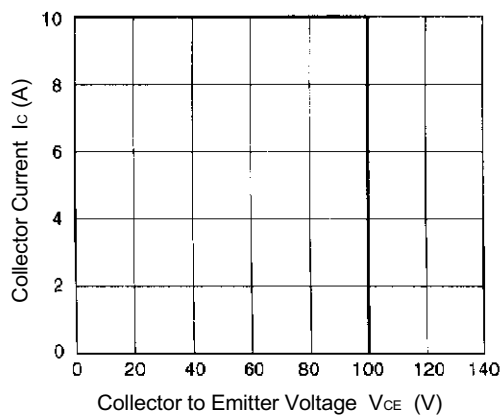
SWITCHING TIME (t_{on}, t_{stg}, t_f) TEST CIRCUIT



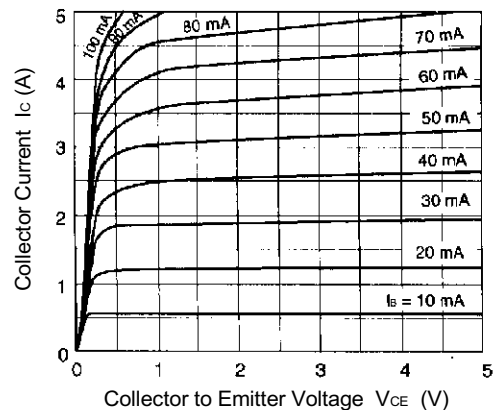
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)



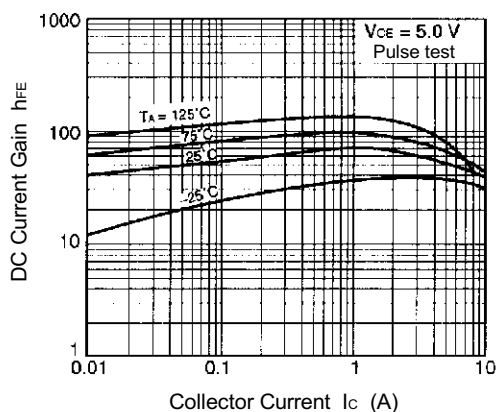
REVERSE BIAS SAFE OPERATING AREAS



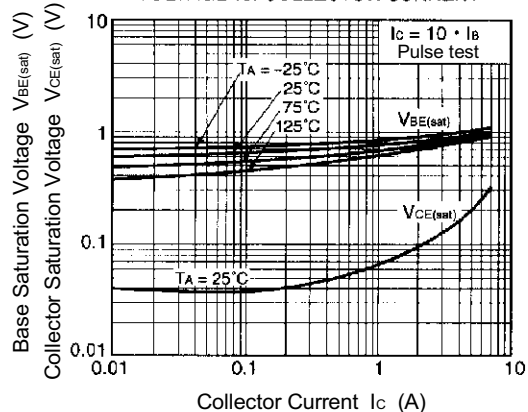
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



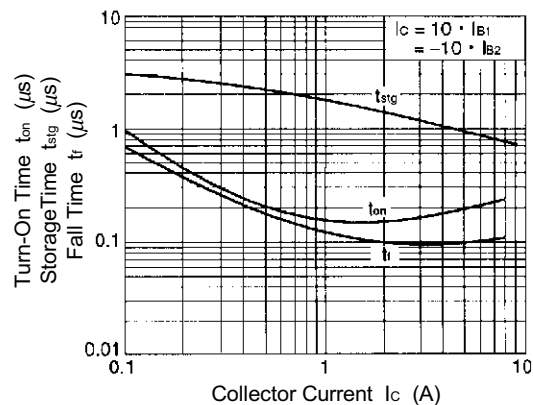
DC CURRENT GAIN vs. COLLECTOR CURRENT



BASE AND COLLECTOR SATURATION VOLTAGE vs. COLLECTOR CURRENT

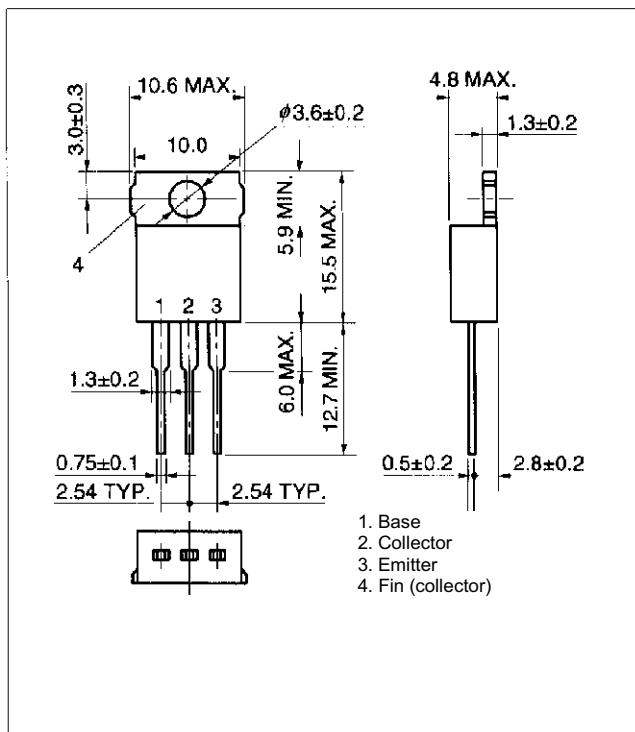


TURN ON TIME, STORAGE TIME AND FALL TIME vs. COLLECTOR CURRENT



PACKAGE DRAWING (UNIT: mm)

TO-220AB (MP-25)



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